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To: Examiner Thanh Y. Tran	Total Pages Sent:	14
Technology Center 2800	(including cover sheet)	
Facsimile Number: (571) 273-8300	Transmission Date:	April 10, 2006

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:	Haupt	Docket No.:	INTECH 3.0-104 (2003 P 51718 US)
Serial No.:	10/766,053	Art Unit:	2822
Date Filed:	January 28, 2004		
Title:	Method for N+ Doping of Amorphous Silicon and Polysilicon Electrodes in Deep Trenches		

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that the following papers are being transmitted by facsimile to the U.S. Patent and Trademark Office at (571) 273-8300 on the date shown above:

- Certification of Facsimile Transmission (1 page)
- Amendment (10 pages)
- Information Disclosure Statement (2 duplicate pages)
- PTO/SB08a with one reference cited (1 page)

Respectfully submitted,

Theresa O'Connor
Legal Assistant

Confirmation Respectfully Requested

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